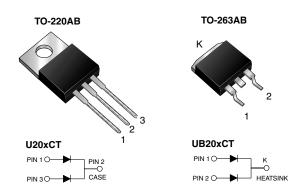


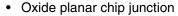
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## **Dual Common-Cathode Ultrafast Plastic Rectifier**



| PRIMARY CHARACTERISTICS                 |                     |  |  |  |
|---|---------------------|--|--|--|
| I <sub>F(AV)</sub>                      | 10 A x 2            |  |  |  |
| $V_{RRM}$                               | 100 V, 150 V, 200 V |  |  |  |
| I <sub>FSM</sub>                        | 100 A               |  |  |  |
| t <sub>rr</sub>                         | 26 ns               |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> = 10 A | 0.834 V             |  |  |  |
| T <sub>J</sub> max.                     | 150 °C              |  |  |  |

#### **FEATURES**





· Soft recovery characteristics

· Low switching losses, high efficiency

High forward surge capability

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)

Solder dip 260 °C, 40 s (for TO-220AB package)

Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, dc-to-dc converters or polarity protection specifically for DCM application.

#### **MECHANICAL DATA**

Case: TO-220AB and TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| <b>MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)                                     |                                   |               |           |           |      |  |
|--|-----------------------------------|---------------|-----------|-----------|------|--|
| PARAMETER  | SYMBOL                            | U(B)20BCT     | U(B)20CCT | U(B)20DCT | UNIT |  |
| Maximum repetitive peak reverse voltage  | V <sub>RRM</sub>                  | 100           | 150       | 200       | V    |  |
| Max. average forward rectified current (Fig. 1) total device per diode                                     | I <sub>F(AV)</sub>                | 20<br>10      |           |           | Α    |  |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode                | I <sub>FSM</sub>                  | 100           |           | А         |      |  |
| Electrostatic discharge capacitor voltage, human body model: C = 150 pF, R = 1.5 k $\Omega$ (contact mode) | V <sub>C</sub>                    | 8             |           | kV        |      |  |
| Operating junction and storage temperature range   | T <sub>J</sub> , T <sub>STG</sub> | - 55 to + 150 |           |           | °C   |  |

Document Number: 89017 Revision: 13-May-08

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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted) |  |   |                 |                |           |      |  |
|---|--|---|-----------------|----------------|-----------|------|--|
| PARAMETER   | TEST CONDITIONS  |   | SYMBOL          | TYP.           | MAX.      | UNIT |  |
| Instantaneous forward voltage per diode (1)                                       | I <sub>F</sub> = 5.0 A<br>I <sub>F</sub> = 10 A  | T <sub>J</sub> = 25 °C                            | V <sub>F</sub>  | 0.854<br>0.931 | -<br>1.00 | · v  |  |
|   | I <sub>F</sub> = 5.0 A<br>I <sub>F</sub> = 10 A  | T <sub>J</sub> = 100 °C                           |                 | 0.760<br>0.834 | -<br>0.91 |      |  |
| Reverse current per diode (2)   | rated V <sub>R</sub>   | T <sub>J</sub> = 25 °C<br>T <sub>J</sub> = 100 °C | I <sub>R</sub>  | 1.2<br>120     | 15<br>500 | μΑ   |  |
| Reverse recovery time per diode   | $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$  |   | t <sub>rr</sub> | 26             | 35        | ns   |  |
| Reverse recovery time per diode   | $I_F = 10 \text{ A}, \text{ dldt} = 20 \text{ A/}\mu\text{s},$<br>$V_R = 200 \text{ V}, I_{rr} = 0.1 I_{RM}$ |   | t <sub>rr</sub> | 73             | 80        | ns   |  |
| Stored charge per diode   |  |   | Q <sub>rr</sub> | 30             | -         | nC   |  |
| Forward recovery time per diode   | $I_F = 10 \text{ A}, \text{ dI/dt} = 80 \text{ A/}\mu\text{s},$<br>$V_F = 1.1 \text{ x } V_F \text{ max}.$   |   | t <sub>fr</sub> | 160            | -         | ns   |  |
| Peak forward voltage per diode  |  |   | $V_{FP}$        | 2.6            | -         | V    |  |

#### Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted) |               |                |  |      |  |
|---|---------------|----------------|--|------|--|
| PARAMETER   | SYMBOL        | U20xCT UB20xCT |  | UNIT |  |
| Typical thermal resistance per diode                                    | $R_{	hetaJC}$ | 3.0            |  | °C/W |  |

| ORDERING INFORMATION (Example) |               |             |              |               |               |  |
|--------------------------------|---------------|-------------|--------------|---------------|---------------|--|
| PACKAGE                        | PREFERRED P/N | UNIT WEIGHT | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |
| TO-220AB                       | U20DCT-E3/4W  | 1.87        | 4W           | 50/tube       | Tube          |  |
| TO-263AB                       | UB20DCT-E3/4W | 1.37        | 4W           | 50/tube       | Tube          |  |
| TO-263AB                       | UB20DCT-E3/8W | 1.37        | 8W           | 800/reel      | Tape and reel |  |

## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

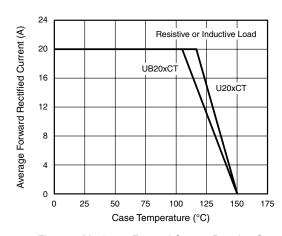


Figure 1. Maximum Forward Current Derating Curve

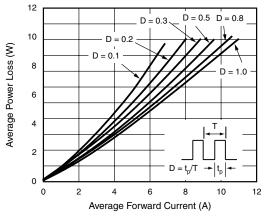


Figure 2. Forward Power Loss Characteristics Per Diode



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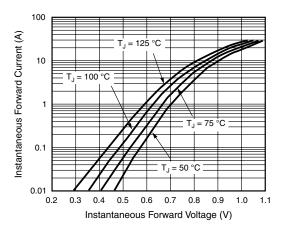


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

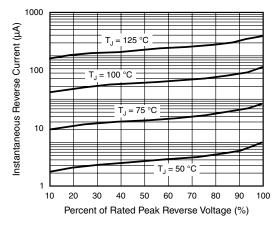


Figure 4. Typical Reverse Characteristics Per Diode

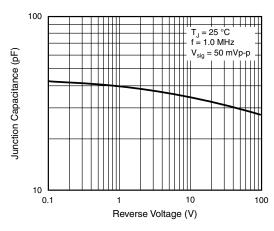


Figure 5. Typical Junction Capacitance Per Diode

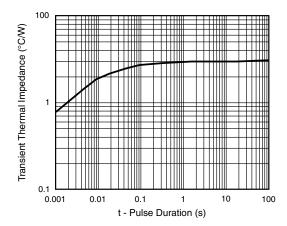


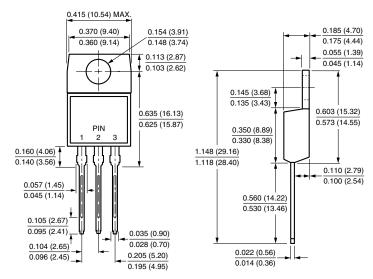
Figure 6. Typical Junction Capacitance Per Diode

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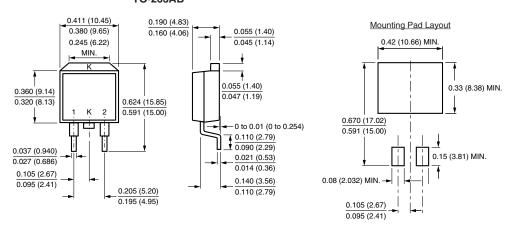


### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### **TO-220AB**



#### TO-263AB





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Revision: 02-Oct-12 Document Number: 91000